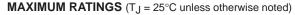
Preferred Device

Silicon Controlled Rectifiers

Reverse Blocking Thyristors

Designed primarily for half-wave ac control applications, such as motor controls, heating controls and power supply crowbar circuits.

- Glass Passivated Junctions with Center Gate Fire for Greater Parameter Uniformity and Stability
- Small, Rugged, Thermowatt Constructed for Low Thermal Resistance, High Heat Dissipation and Durability
- Blocking Voltage to 800 Volts
- 80 A Surge Current Capability
- Insulated Package Simplifies Mounting
- **%** Indicates UL Registered File #E69369
- Device Marking: Logo, Device Type, e.g., MCR218-6, Date Code



Rating	Symbol	Value	Unit
Peak Repetitive Off–State Voltage ⁽¹⁾ (T _J = -40 to +125°C, Sine Wave 50 to 60 Hz, Gate Open) MCR218–6FP	VDRM, VRRM	400	Volts
MCR218-10FP		800	
On-State RMS Current (T _C = +70°C)(2) (180° Conduction Angles)	IT(RMS)	8.0	Amps
Peak Nonrepetitive Surge Current (1/2 Cycle, Sine Wave 60 Hz, T _J = 125°C)	ITSM	100	Amps
Circuit Fusing (t = 8.3 ms)	I ² t	26	A ² s
Forward Peak Gate Power $(T_C = +70^{\circ}C, \text{ Pulse Width } \leq 1.0 \mu\text{s})$	PGM	5.0	Watts
Forward Average Gate Power (T _C = +70°C, t = 8.3 ms)	P _G (AV)	0.5	Watt
Forward Peak Gate Current ($T_C = +70^{\circ}C$, Pulse Width $\leq 1.0 \mu s$)	I _{GM}	2.0	Amps
RMS Isolation Voltage ($T_A = 25^{\circ}C$, Relative Humidity $\leq 20\%$) (%)	V _(ISO)	1500	Volts
Operating Junction Temperature	TJ	-40 to +125	°C
Storage Temperature Range	T _{stg}	-40 to +150	°C

- (1) VDRM and VRRM for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; however, positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.
- (2) The case temperature reference point for all T_C measurements is a point on the center lead of the package as close as possible to the plastic body.



ON Semiconductor

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ISOLATED SCRs (9\) 8 AMPERES RMS 400 thru 800 VOLTS





ISOLATED TO-220 Full Pack CASE 221C STYLE 2

PIN ASSIGNMENT				
1 Cathode				
2	Anode			
3	Gate			

ORDERING INFORMATION

Device	Device Package	
MCR218-6FP	ISOLATED TO220FP	500/Box
MCR218-10FP	ISOLATED TO220FP	500/Box

Preferred devices are recommended choices for future use and best overall value.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$R_{\theta JC}$	2	°C/W
Thermal Resistance, Case to Sink	$R_{\theta}CS$	2.2 (typ)	°C/W
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	60	°C/W
Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 10 Seconds	TL	260	°C

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted.)

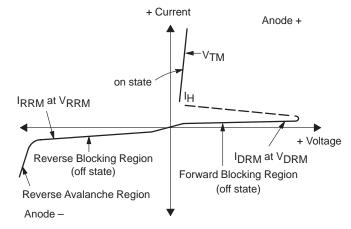
Characteristic	Symbol	Min	Тур	Max	Unit
DFF CHARACTERISTICS	•	•			•
Peak Repetitive Forward or Reverse Blocking Current $(V_D = Rated \ V_{DRM}, Gate \ Open)$ $T_J = 25^{\circ}C$ $T_J = 125^{\circ}C$	I _{DRM,} I _{RRM}		_	10 2	μA mA
ON CHARACTERISTICS	•	•			•
Peak Forward On–State Voltage ⁽¹⁾ (I _{TM} = 16 A Peak)	VTM	_	1	1.8	Volts
Gate Trigger Current (Continuous dc) (V _{AK} = 12 Vdc, R _L = 100 Ohms)	lGT	_	10	25	mA
Gate Trigger Voltage (Continuous dc) (V _{AK} = 12 Vdc, R _L = 100 Ohms)	V _{GT}		_	1.5	Volts
Gate Non-Trigger Voltage (V _{AK} = 12 Vdc, R _L = 100 Ohms, T _J = 125°C)	V _{GD}	0.2		_	Volts
Holding Current (V _{AK} = 12 Vdc, Initiating Current = 200 mA, Gate Open)	lн		16	30	mA
Turn-On Time (I _{TM} = 8 A, I _{GT} = 40 mAdc)	^t gt	_	1.5	_	μs
Turn-Off Time (V_D = Rated V_{DRM} , I_{TM} = 8 A, I_R = 8 A) I_J = 25°C I_J = 125°C	tq	_	15 35	_	μs
DYNAMIC CHARACTERISTICS		· · · · · ·			
Critical Rate-of-Rise of Off-State Voltage (Gate Open, Vp = Rated Vppm, Exponential Waveform)	dv/dt	_	100	_	V/µs

Critical Rate-of-Rise of Off-State Voltage	dv/dt	_	100	_	V/μs
(Gate Open, V_D = Rated V_{DRM} , Exponential Waveform)					

⁽¹⁾ Pulse Test: Pulse Width = 1 ms, Duty Cycle < 2%.

Voltage Current Characteristic of SCR

Symbol	Parameter
V _{DRM}	Peak Repetitive Off State Forward Voltage
IDRM	Peak Forward Blocking Current
VRRM	Peak Repetitive Off State Reverse Voltage
I _{RRM}	Peak Reverse Blocking Current
V _{TM}	Peak on State Voltage
lΗ	Holding Current



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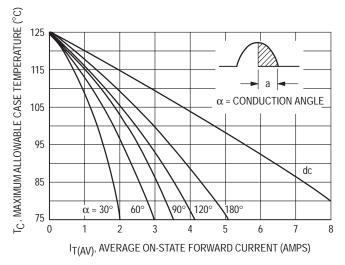


Figure 1. Current Derating

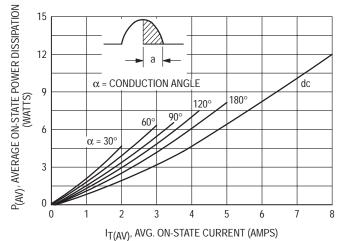


Figure 2. On-State Power Dissipation

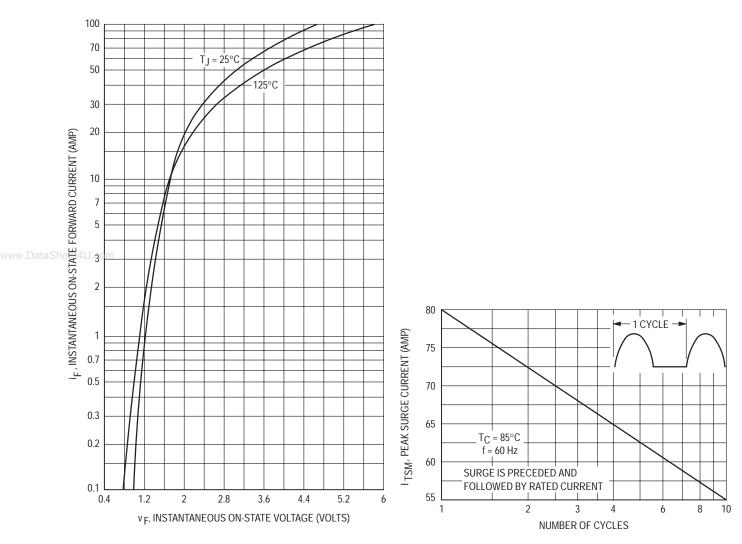


Figure 3. Maximum On-State Characteristics

Figure 4. Maximum Non-Repetitive Surge Current

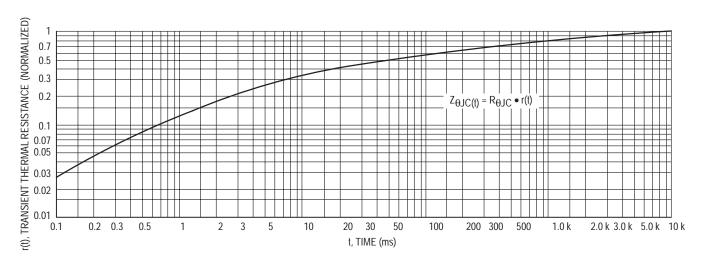
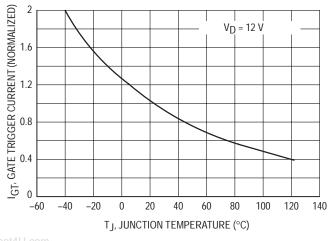
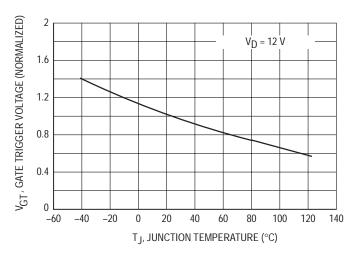


Figure 5. Thermal Response





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Figure 6. Typical Gate Trigger Current versus Temperature

Figure 7. Typical Gate Trigger Voltage versus Temperature

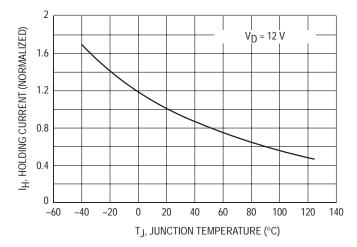
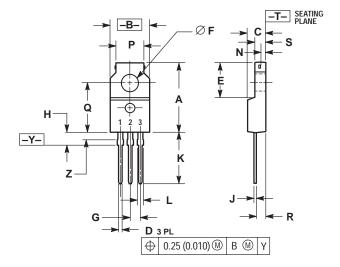


Figure 8. Typical Holding Current versus Temperature

PACKAGE DIMENSIONS

ISOLATED TO-220 Full Pack

CASE 221C-02 ISSUE C



- NOTES:

 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: INCH.

 3. LEAD DIMENSIONS UNCONTROLLED WITHIN DIMENSION Z.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.680	0.700	17.28	17.78
В	0.388	0.408	9.86	10.36
С	0.175	0.195	4.45	4.95
D	0.025	0.040	0.64	1.01
Ε	0.340	0.355	8.64	9.01
F	0.140	0.150	3.56	3.81
G	0.100 BSC		2.54	BSC
Н	0.110	0.155	2.80	3.93
J	0.018	0.028	0.46	0.71
K	0.500	0.550	12.70	13.97
L	0.045	0.070	1.15	1.77
N	0.049		1.25	
Р	0.270	0.290	6.86	7.36
Q	0.480	0.500	12.20	12.70
R	0.090	0.120	2.29	3.04
S	0.105	0.115	2.67	2.92
Z	0.070	0.090	1.78	2.28

STYLE 2:

PIN 1. CATHODE 2. ANODE 3. GATE

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Notes

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